NSN 5962-01-111-4911

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-111-4911

Dedu Leveth.
0.785 inches
0.280 inches
Body Height:
Between 0.140 inches and 0.180 inches
Maximum Power Dissipation Rating: 270.0 milliwatts
Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
6 input Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
25.00 nanoseconds propagation delay time, low to high level output and 25.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type: Rom
Memory Capacity:
Unknown
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
14 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

NSN 5962-01-111-4911

Memory Microcircuit - Page 2 of 2

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